

# 1.2V Drive Nch MOSFET

## RUM002N05

### ● Structure

Silicon N-channel MOSFET

### ● Features

- 1) High speed switing.
- 2) Small package(VMT3).
- 3) Ultra low voltage drive(1.2V drive).

### ● Application

Switching

### ● Packaging specifications

Type	Package	Taping
	Code	T2L
	Basic ordering unit (pieces)	8000
RUM002N05		○

### ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		$V_{DSS}$	50	V
Gate-source voltage		$V_{GSS}$	±8	V
Drain current	Continuous	$I_D$	±200	mA
	Pulsed	$I_{DP}$ *1	±800	mA
Source current (Body Diode)	Continuous	$I_S$	125	mA
	Pulsed	$I_{SP}$ *1	800	mA
Power dissipation		$P_D$ *2	150	mW
Channel temperature		$T_{ch}$	150	°C
Range of storage temperature		$T_{stg}$	-55 to +150	°C

 \*1  $P_W \leq 10 \mu s$ , Duty cycle  $\leq 1\%$ 

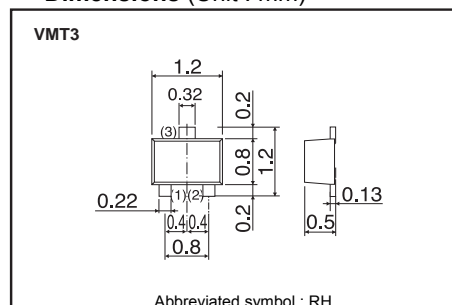
\*2 Each terminal mounted on a recommended land.

### ● Thermal resistance

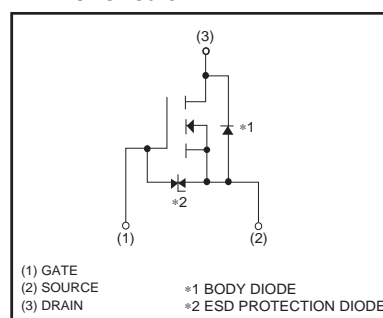
Parameter	Symbol	Limits	Unit
Channel to Ambient	$R_{th}(ch-a)^*$	833	°C / W

\* Each terminal mounted on a recommended land.

### ● Dimensions (Unit : mm)



### ● Inner circuit



## ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	$I_{GSS}$	-	-	$\pm 10$	$\mu A$	$V_{GS} = \pm 8V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	50	-	-	V	$I_D = 1mA, V_{GS} = 0V$
Zero gate voltage drain current	$I_{DSS}$	-	-	1	$\mu A$	$V_{DS} = 50V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	0.3	-	1.0	V	$V_{DS} = 10V, I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	1.6	2.2	$\Omega$	$I_D = 200mA, V_{GS} = 4.5V$
		-	1.7	2.4		$I_D = 200mA, V_{GS} = 2.5V$
		-	1.9	2.7		$I_D = 100mA, V_{GS} = 1.8V$
		-	2.0	4.0		$I_D = 40mA, V_{GS} = 1.5V$
		-	2.4	7.2		$I_D = 20mA, V_{GS} = 1.2V$
Forward transfer admittance	$ Y_{fs} ^*$	0.4	-	-	S	$I_D = 200mA, V_{DS} = 10V$
Input capacitance	$C_{iss}$	-	25	-	pF	$V_{DS} = 10V$
Output capacitance	$C_{oss}$	-	6	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	$C_{rss}$	-	3	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	4	-	ns	$I_D = 100mA, V_{DD} = 30V$
Rise time	$t_r^*$	-	6	-	ns	$V_{GS} = 4.5V$
Turn-off delay time	$t_{d(off)}^*$	-	15	-	ns	$R_L = 300\Omega$
Fall time	$t_f^*$	-	55	-	ns	$R_G = 10\Omega$

\*Pulsed

## ●Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	$V_{SD}^*$	-	-	1.2	V	$I_s = 200mA, V_{GS} = 0V$

\*Pulsed

## ●Electrical characteristic curves

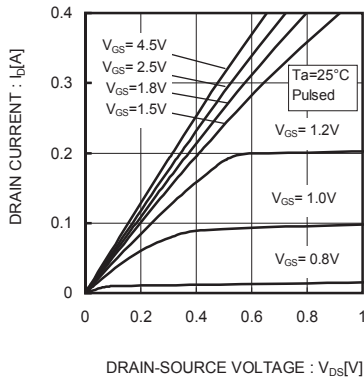


Fig.1 Typical Output Characteristics( I )

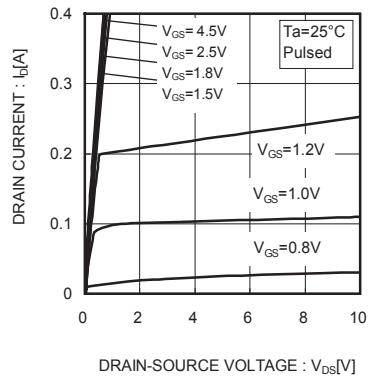


Fig.2 Typical Output Characteristics( II )

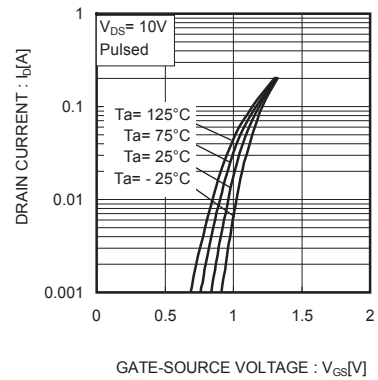


Fig.3 Typical Transfer Characteristics

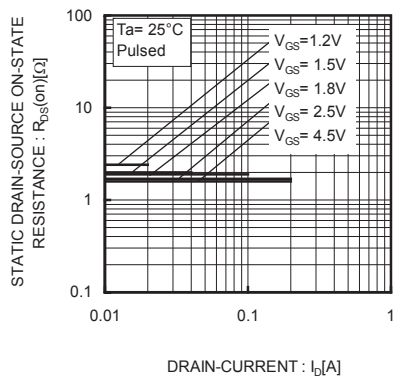


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current( I )

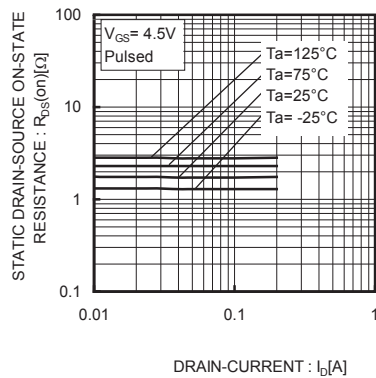


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current( II )

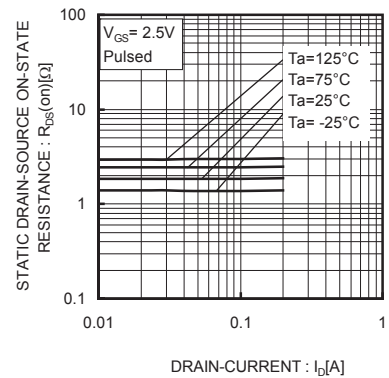


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current( III )

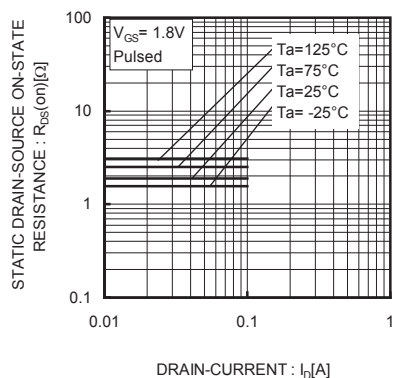


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current( IV )

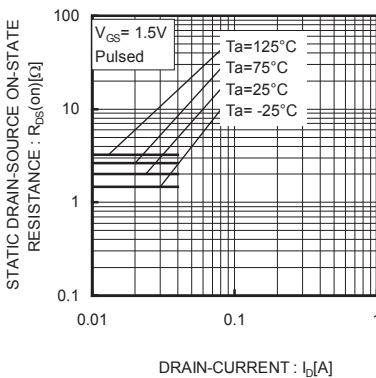


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current( V )

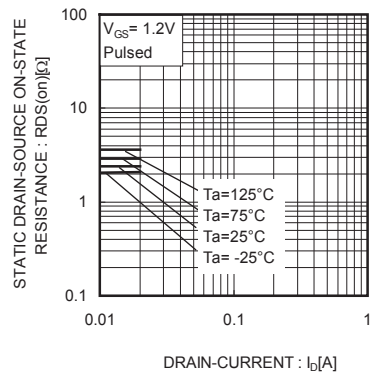


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current( VI )

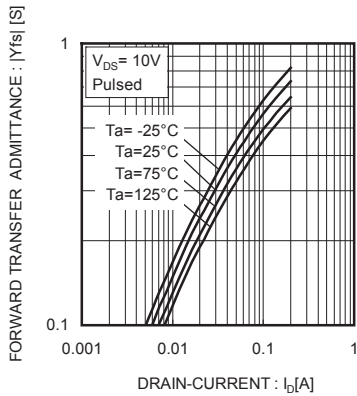


Fig.10 Forward Transfer Admittance vs. Drain Current

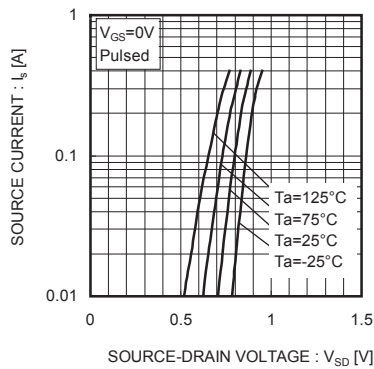


Fig.11 Reverse Drain Current vs. Source-Drain Voltage

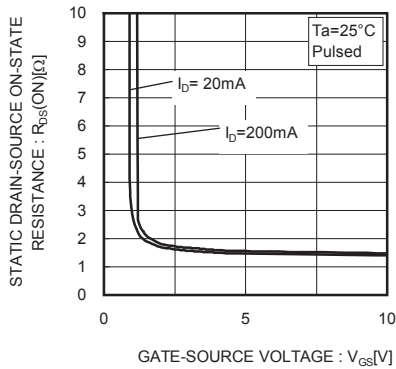


Fig.12 Static Drain-Source On-State Resistance vs. Gate Source Voltage

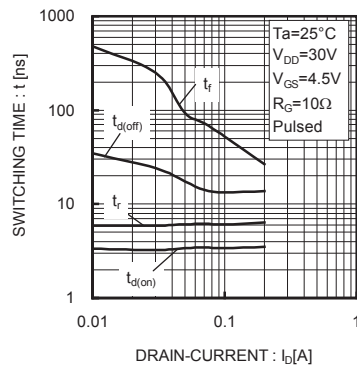


Fig.13 Switching Characteristics

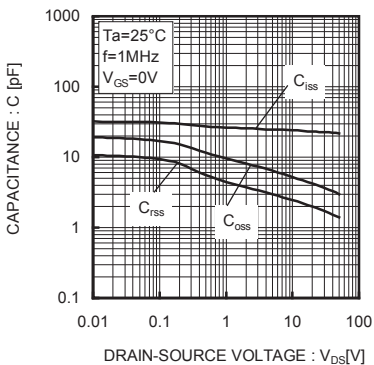


Fig.14 Typical Capacitance vs. Drain-Source Voltage

### ●Measurement circuits

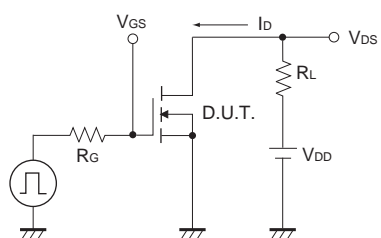


Fig.1-1 Switching time measurement circuit

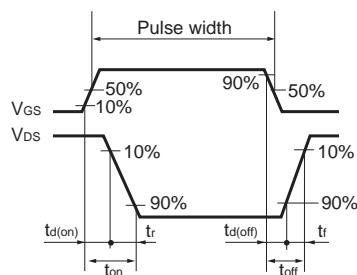


Fig.1-2 Switching waveforms

### ●Notice

This product might cause chip aging and breakdown under the large electrified environment.  
Please consider to design ESD protection circuit.

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